AmPALC29M16

24-Pin E²-Based CMOS Programmable Array Logic ADVANCE INFORMATION

Distinctive Characteristics

- High-performance semi-custom logic replacement;
 Electrically Erasable (E²) technology allows reprogrammability
- 16 bidirectional user-programmable I/O logic macrocells for Combinatorial/Registered/Latched operation
- Output Enable controlled by a pin or product terms
- Variable product term distribution for increased design flexibility
- Programmable clock selection with two clocks/latch enables (LEs) and LOW/HIGH clock/LE polarity
- Register/Latch PRELOAD permits full logical verification
- Available in high-speed (tpD = 35 ns, f_{MAX} = 20 MHz) and standard-speed (tpD = 45 ns, f_{MAX} = 15.0 MHz) versions
- 100% post-programming functional yield (PPFY), fast programming and excellent reliability assured through proven E²PROM technology
- Full-function AC and DC testing at the factory
- 24-pin 300-mil DIP and 28-pin chip carrier packages

General Description

The AmPALC29M16 is a high-speed E²-based CMOS Programmable Array Logic device designed for general logic replacement in TTL or CMOS digital systems. It offers high-speed, low power consumption, high programming yield, fast programming and excellent reliability. Programmable logic devices (PLDs) combine the flexibility of custom logic with the off-the-shelf availability of standard products, providing major advantages over other semicustom solutions such as gate arrays and standard cells, including reduced development time and low upfront development cost.

The AmPALC29M16 uses the familiar sum-of-products (AND-OR) structure, allowing users to customize logic functions by programming the device for specific applications. It provides up to twenty-nine array inputs and sixteen outputs. It incorporates AMD's unique input/output logic macrocell which provides flexible input/output structure and polarity, flexible feedback selection, multiple Output Enable choices, and a programmable clocking scheme. The macrocells can be individually programmed as "Combinatorial", "Registered", or "Latched" with active-HIGH or active-LOW polarity. The flexibility of the

logic macrocells permits the system designer to tailor the device to particular application requirements.

Increased logic power has been built into the AmPAL29M16 by providing a variable number of logical product terms per output. Eight outputs have eight product terms each, four outputs have twelve product terms each, and the other four outputs have sixteen product terms each. This variable product-term distribution allows complex functions to be implemented in a single PAL device. Each output can be dynamically controlled by an Output Enable pin or Output Enable product terms. Each output can also be permanently enabled or diasabled.

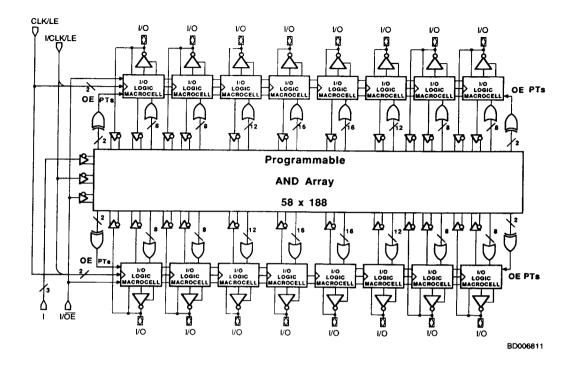
System operation has been enhanced by the addition of common asynchronous-PRESET and RESET product terms and a power-up RESET feature. The AmPAL29M16 also incorporates PRELOAD and Observability functions which permit full logical verification of the design.

The AmPALC29M16 is offered in the space-saving 300-Mil DIP package as well as chip carrier surface-mount packages.

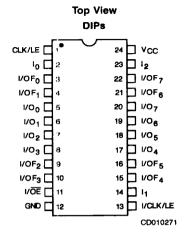
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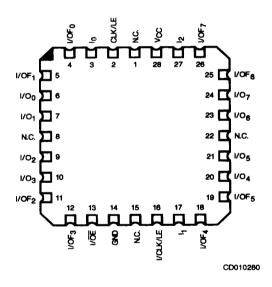
Block Diagram



Connection Diagrams



LCC*



*Also available in PLCC. Pinouts identical to LCC.

Note: Pin 1 is marked for orientation.

Pin Description

The following describes the functionality of all the pins on the 24-pin DIP. The 28-pin chip carrier has the same functionality with NO CONNECTS on pins 1,8,15,22.

CLK/LE (PIN 1):

Used as dedicated clock/latch enable pin for all registers/ latches on the device if so selected. (See I/O Logic Macrocell Configurations.) This pin is a clock pin for macrocells configured as registers and a latch enable pin for macrocells configured as latches.

I/CLK/LE PIN (PIN 13):

Used as dedicated input or as an alternate clock/latch enable pin for all the registers/latches if so selected. (See I/O Logic Macrocell Configurations.) This pin is a clock pin for macrocells configured as registers and a latch enable pin for macrocells configured as latches.

I/OE PIN (PIN 11):

Used as a dedicated input pin to the AND array or as the Output Enable control pin (Active LOW) for all macrocells with pin-controlled Output Enable selected.

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I₀-I₂ (PINS 2,14,23): Dedicated input pins.

I/OF₀-I/OF₇ (PINS 3,4,9,10,15,16,21,22):

Eight bidirectional I/O pins with two independent feedback paths to the AND array. The first feedback path is a dedicated I/O pin feedback to the AND array for combinatorial input. The second feedback path consists of direct register/latch feedback to the array (see Figure 1).

I/O₀-I/O₇ (PINS 5,6,7,8,17,18,19,20):

Eight bidirectional I/O pins with user-programmable register/latch or I/O pin feedback to the AND array (see Figure 1).

V_{CC} (PIN 24):

Supply Voltage

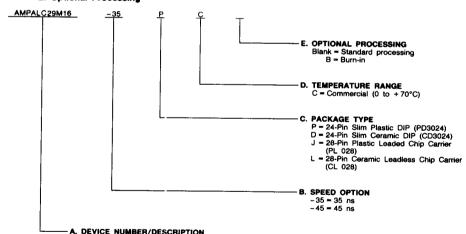
GND (PIN 12): Circuit Ground

Ordering Information

Standard Products

AMD standard products are available in several packages and operating ranges. The order number (Valid Combination) is formed by a combination of: **A. Device Number**

- B. Speed Option (if applicable)
- C. Package Type
- D. Temperature Range
- E. Optional Processing



Valid Combinations AmPALC29M16-35, -45 PC, DC, DCB, JC, LC, LCB

Valid Combinations

Valid Combinations list configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations, to check on newly released combinations, and to obtain additional data on AMD's standard military grade products.

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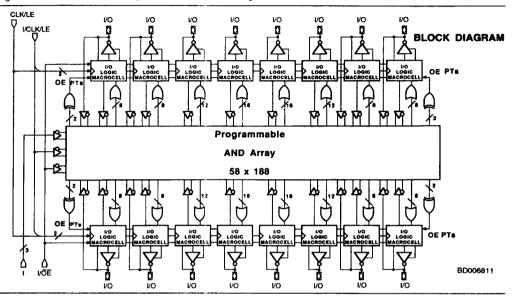
Functional Description

Inputs

The AmPAL29CM16 has 29 inputs to drive each product term (up to 58 inputs with both TRUE and complement versions available to the AND array) as shown in the block diagram below. Of these 29 inputs, 3 are dedicated inputs, 16 are from 8 I/O logic macrocells with 2 feedbacks, 8 are from other I/O

logic macrocells with single feedback, 1 is for I/CLOCK/LE and 1 is for I/ \overline{OE} input.

Initially the AND-array gates are disconnected from all the inputs. This condition represents a logical TRUE to the AND array. By selectively programming the E²cells, the AND array may be connected to either the TRUE input or the complement input. When both the TRUE and complement inputs are connected, a logical FALSE results at the output of the AND gate.



Product Terms

The degree of programmability and complexity of a PAL device is determined by the number of connections that form the programmable-AND and OR gates. Each programmable-AND gate is called a product term. The AmPALC29M16 has 188 product terms. 176 of these product terms provide logic capability and 12 are architectural or control product terms. Among the 12 control product terms, 2 are for common Asynchronous-PRESET and RESET, 1 is for Observability, and 1 is for PRELOAD. The other 8 are common Output Enable product terms. The Output Enable of each bank of 4 macrocells can be programmed to be controlled by a common Output Enable pin or 2 AND/XOR product terms. It may be also permanently enabled or permanently disabled.

Each product term on the AmPALC29M16 consists of a 58-input AND gate. The outputs of these AND gates are connected to a fixed-OR plane. Product terms are allocated to OR gates in a variable distribution across the device ranging from 8-to-16 wide, with an average of 11 logical product terms per output. Increased number of product terms per output allows more complex functions to be implemented in a single PAL device. This flexibility aids in implementing functions such as counters, exclusive-OR functions, or complex state machines, where different states require different numbers of product terms.

Common asynchronous-PRESET and RESET product terms are connected to all Registered/Latched inputs/outputs. When the asynchronous-PRESET product term is asserted (HIGH) all the registers/latches will immediately be loaded with a HIGH, independent of the clock. When the asynchronous-RESET product term is asserted (HIGH) all the registers/latches will be immediately loaded with a LOW, independent of the clock. The actual output state will depend on the macrocell polarity selection. The latches must be in latched mode (not transparent mode) for the RESET/PRESET, PRELOAD, and power-up RESET modes to be meaningful.

Input/Output Logic Macrocells

The I/O logic macrocell allows the user the flexibility of defining the architecture of each input or output on an individual basis. It also provides the capability of using the associated pin either as an input or an output.

The AmPALC29M16 has 16 macrocells, one for each I/O pin. Each I/O macrocell can be programmed for combinatorial, registered or latched operation (see Figure 1). Combinatorial output is desired when the PAL device is used to replace combinatorial glue logic. Registers are used in synchronous logic applications while latches are used in asynchronous applications where speed is critical. The output polarity for each macrocell in each of the three modes of operation is

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user-selectable, allowing complete flexibility of the macrocell configuration.

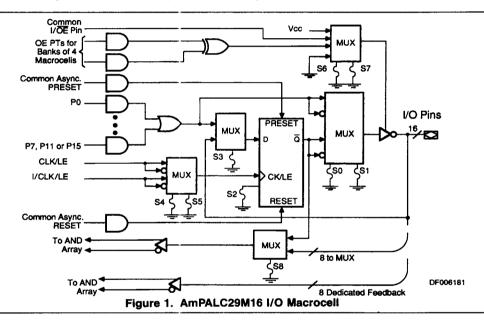
Eight of the macrocells (I/OF₀-I/OF₇) have two independent feedback paths to the AND array (see Figure 1). The first is a dedicated I/O pin feedback to the AND array for combinatorial input. The second path consists of a direct register/latch feedback to the array. If the pin is used as a dedicated input using the first feedback path, the register/latch feedback path is still available to the AND array. This path provides the capability of using the register/latch as a buried state register/latch. The other eight macrocells have a single feedback path to the AND array. This feedback is user-selectable as either an I/O pin or a register/latch feedback.

Each macrocell can provide true input/output capability. The user can select each macrocell register/latch to be driven by either the output generated by the AND-OR array or the I/O pin. When the I/O pin is selected as the input, the feedback path provides the register/latch input to the array. When used

as an input, each macrocell is also user-programmable for registered, latched, or combinatorial input.

The AmPALC29M16 has one dedicated CLK/LE pin and one I/CLK/LE pin. All macrocells have a programmable select to choose between these two pins as the clock or the latch enable signal. These pins are clock pins for macrocells configured as registers and latch enable pins for macrocells configured as latches. The polarity of these CLK/LE signals is also individually programmable. Thus different registers can be driven by multiple clocks and clock phases.

The Output-Enable mode of each of the macrocells can be selected by the user. The I/O pin can be configured as an output pin (permanently enabled) or as an input pin (permanently disabled). It can also be configured as a dynamic I/O controlled by the Output Enable pin or by two AND-XOR product terms which are available for each bank of four I/O logic macrocells.



I/O Logic Macrocell Configuration

AMD's unique I/O macrocell offers major benefits through its versatile, programmable input/output cell structure, multiple clock choices, flexible Output Enable and feedback selection. Eight I/O macrocells with single feedback contain nieze-cells, while the other eight macrocells contain eight E²cells for programming the input/output functions (see Table 1, Figure 2).

E²cell S1 controls whether the macrocell will be combinatorial or registered/latched. S0 controls the output polarity (active-HIGH or active-LOW). S2 determines whether the output is a register or a latch. S3 allows the use of the macrocell as an input register/latch or as an output register/latch. It selects the direction of the data path through the register/latch. If

connected to the usual AND-OR array output, the register/latch is an output connected to the I/O pin. If connected to the I/O pin, the register/latch becomes an input register/latch to the AND array using the feedback data path.

Programmable E²cells S4 and S5 allow the user to select one of the four CLK/LE signals for each macrocell. S6 and S7 are used to control Output Enable as pin controlled, two product term controlled, permanently enabled or permanently disabled. S8 is a feedback multiplexer for the macrocells with a single feedback path only.

In the virgin erased state (charged, disconnected), an architectural cell is said to have a value of "1"; In the programmed state (discharged, connected), an architectural cell is said to have a value of "0".

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Table 1. AmPALC29M16 I/O Logic Macrocell Architecture Selections

S3	I/O Cell			
1	Output Cell			
0	Input Cell			

S2	Storage Element
1	Register
0	Latch

S1	Output Type
1	Combinatorial
0	Register/Latch

S0	Output Polarity
1	Active LOW
0	Active HIGH

S8	Feedback*
1 0	Register/Latch

^{*}Applies to macrocells with single feedback only.

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Table 1. AmPALC29M16 I/O Logic Macrocell Clock Polarity & Output Enable Selections

(Cont'd.)

85	Clock Edge/Latch Enable Level
1	CLK/LE pin positive-going edge, active-HIGH LE
0	CLK/LE pin negative-going edge, active-LOW LE
1	I/CLK/LE pin positive-going edge, active-HIGH LE
0	I/CLK/LE pin negative-going edge, active-LOW LE
	1 0

86	S 7	Output Buffer Control
1	1	Pin - Controlled 3-State Enable
1	0	XOR PT-Controlled 3-State Enable
0	1	Permanently Enabled (Output only)
0	0	Permanently Disabled (input only)

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^{1 =} Erased State (Charged or disconnected)

^{0 =} Programmed State (Discharged or connected)

Some Possible Configurations of the Input/Output Logic Macrocell

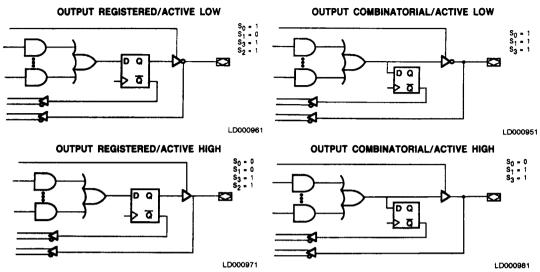


Figure 2a. Dual Feedback Macrocells

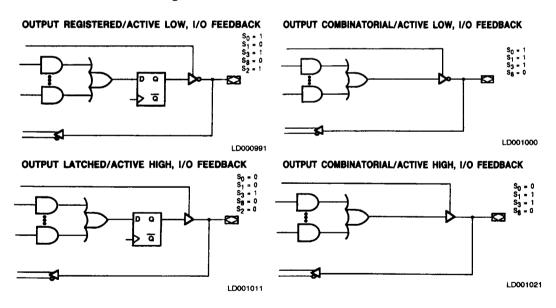


Figure 2b. Single Feedback Macrocells

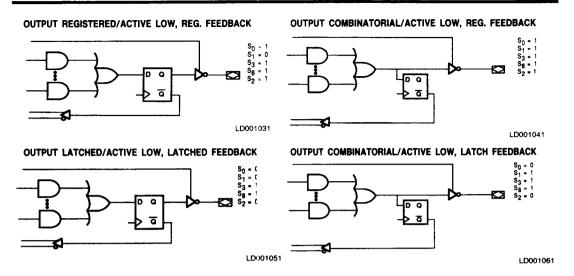


Figure 2b. Single Feedback Macrocells (Cont'd.)

INPUT REGISTERED/LATCHED

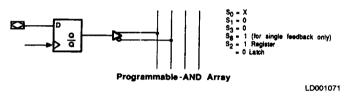


Figure 2c. All Macrocells

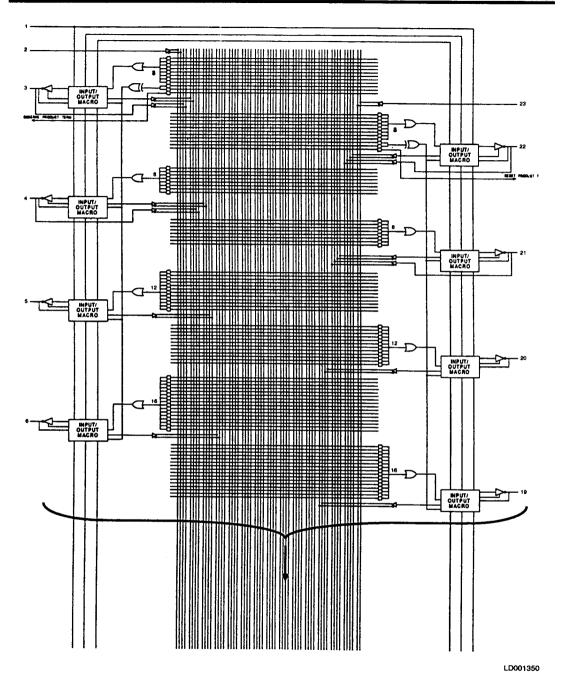


Figure 3. AmPALC29M16 Logic Diagram

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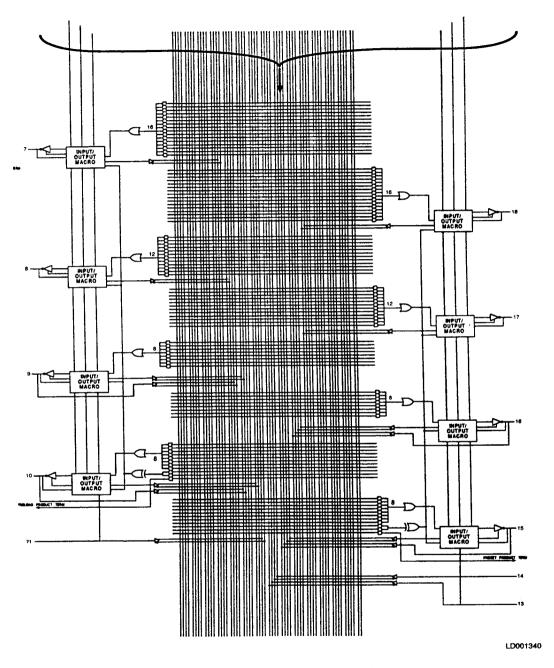


Figure 3. AmPALC29M16 Logic Diagram (Cont'd.)

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Designed in Testability and DebuggingPRELOAD

To simplify testing, the AmPALC29M16 is designed with PRE-LOAD circuitry that provides an easy method for testing logical functionality. Both product-term controlled and supervoltage-enabled PRELOAD modes are available. This offers even more test capability than previously implemented in AMD's PAL devices. The TTL-level PRELOAD product term can be useful during debugging, where supervoltages may not be available.

PRELOAD allows any arbitrary state value to be loaded into the registers/latches of the device. A typical functional-test sequence would be to verify all possible state transitions for the device being tested. This requires the ability to set the state registers into an arbitrary "present state" value and to set the devices inputs into any arbitrary "present input" value. Once this is done, the state machine is clocked into a new state, or "next state", which can be checked to validate the transition from the "present state". In this way any transition can be checked.

Since PRELOAD can provide the capability to go directly to any desired arbitrary state, test sequences may be greatly shortened. Also, all possible states can be tested, thus greatly reducing test time and development costs and guaranteeing proper in-system operation.

Observability

The output register/latch observability product term, when asserted, suppresses the combinatorial output data from appearing on the I/O pin and allows the observation of the contents of the register/latch on the output pin for each of the logic macrocells. This unique feature allows for easy debugging and tracing of the buried state machines. In addition, a capability of supervoltage observability is also provided.

Power-Up Reset

All the device registers/latches have been designed to reset during device power-up. Following the power-up, all registers/latches will be cleared (Q=0), setting the outputs to a state determined by the output select multiplexer. This feature provides extra flexibility to the designer and is especially valuable in simplifying state machine initialization.

Security Cell

A security cell is provided on each device to prevent unauthorized copying of the user's proprietary logic design. Once programmed, the security cell disables the programming, verification, PRELOAD, and the observability modes. The only way to erase the protection cell is by charging the entire array and architecture cells, in which case no proprietary design can be copied. (This cell should be programmed only after the rest of the device has been completely programmed and verified.)

Programmers/Development Systems

(refer to Programmer Reference Guide, page 3-81)

Absolute Maximum Ratings

Storage Temperature	
Ambient Temperature under bia	s55 to +125°C
Supply Voltage with	
Respect to Ground	0.5 V to +7.0 V
DC Output Voltage	0.5 V to V _{CC} + 0.5 V
DC Input Voltage	
(Except Pin I/OE)	
DC Input Voltage (Pin I/OE)	0.6 V to +17 V
DC Input Current	

Stresses above those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to absolute maximum ratings for extended periods may affect device reliability.

Operating Ranges

Commercial (C) Devices	
Temperature (T _A)	0°C to +70°C
Supply Voltage (VCC)	+4.50 to +5.50 V
Military (M) Devices*	

Operating ranges define those limits between which the functionality of the device is guaranteed.

DC Characteristics over operating range unless otherwise specified

HCT Devices*

Parameter Symbol	Parameter Description			Min.	Max.	Units
Voн	Output HIGH Voltage			2.4		٧
			I _{OL} = 6 mA		0.5	
V _{OL}	Output LOW Voltage	V _{CC} = Min. V _{IN} = V _{IH} or V _{IL}	I _{OL} = 4 mA		0.33	v
			I _{OL} = 20 μA		0.1	
VIH	Input HIGH Voltage	Guaranteed Logic HIGH for all Inputs		2.0		٧
VIL	Input LOW Voltage	Guaranteed Logic LOW for all Inputs			0.8	٧
I _I	Input Leakage Current	V _{IN} = 0 to 5.5 V, V	CC = Max.		10	μΑ
10	Output Leakage Current	V _{IN} = 0 to 5.5 V, V	CC = Max.		10	μА
ICCOP	Operating Current Supply	f = f _{MAX} , Outputs Open (I _O = 0)			120	mA
Isc	Output Short Circuit Current	V _{CC} = Max., V _O = 0 V		-30	-90	mA

Capacitance

Parameter Symbol	ymbol Description Test Conditions		Тур.	Units
CIN	Input Capacitance	V _{CC} = 5.00 V., T _A = 25°C	5	ρF
Cout	Output Capacitance	V _{IN} = 0 V @ f = 1 MHz	8	ļ

Note: These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.

^{*}Consult Factory for Military Specifications

^{*} Consult factory for DC specification on HC Devices.

AmPALC29M16

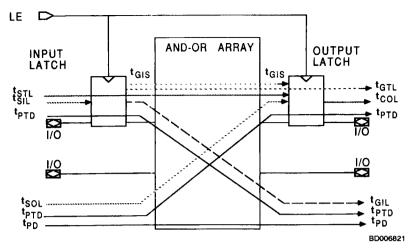
Switching Characteristics over operating range unless otherwise specified; all values are determined under the loading of one TTL gate and a capacitance of 50 pF

Parameter	Parameter	Parameter	-35		-45		
Number	Symbol	Description	Min.	Max.	Min.	Max.	Units
REGISTERED OPERATION (Numbers 1 through 12)							
1 t _{PD}		Input or 1/O Pin to Combinatorial Output		35		45	ns
Output Register							
2	t _{SOR}	Input or I/O Pin to Output Register Setup	27		34		ns
3	tCOR	Output Register Clock to Output		23		32	ns
4	tноя	Data Hold Time for Output Register	0		o		ns
Input Register							
5	tsiR	I/O Pin to Input Register Setup	6		8		ns
6	[‡] CIR	Register Feedback Clock to Combinatorial Output		45		58	ns
7	tHIR	Data Hold Time for Input Register	3		4		ns
Clocking and Fr	equency						
8	^t CIS	Register Feedback to Output Register/Latch Setup	35		45		ns
9	fMAX	Maximum Frequency 1/(tson + tcon)		20		15	MHz
10	fMAXI	Max Internal Frequency 1/tcis		28.5		22.5	MHz
11	ŧсwн	Clock Widtn HIGH	12		15		
12	tCWL	Clock Width LOW	12		15		
		LATCH OPERATION (Numbers	s 13 throu	gh 24)			
13	t _{PD}	Input or I/O Pin to Combinatorial Output		35		45	ns
14	t _{PTD}	Input or I/O Pin to Output via One Transparent Latch		45	,	55	ns
Output Latch							
15	tsol	Input or I/O Pin to Output Latch Setup	27		34		ns
16	^t GOL	Latch Enable to Transparent Mode Output		23		32	ns
17	tHOL	Data Hold Time for Output Latch	0		0		ns
18	tstl.	Input or I/O Pin to Output Latch Setup via Transparent Input Latch	35		45		ns

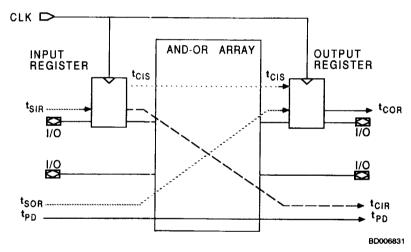
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Parameter Number	Parameter Symbol	Parameter Description	-35		-45		
			Min.	Max.	Min.	Max.	Units
input Latch							
19	tsıl.	I/O Pin to Input Latch Setup	6		8		ns
20	^t GIL	Latch Feedback, Latch Enable Transparent Mode to Combinatorial Output		45		58	ns
21	tHIL	Data Hold Time for Input Latch	3		4		ns
Latch Enable							
22	^t GIS	Latch Feedback Transparent Mode to Output Register/ Latch Setup	35		45		ns
23	[‡] GWH	Latch Enable Width HIGH	12		15		ns
24	^t GWL	Latch Enable Width LOW	12		15	l	ns
	RESET/PRE	SET & OUTPUT ENABLE OPERA	TION (Nui	mbers 25 ti	nrough 32)		
25	[†] APO	Input or I/O Pin to Output Register/Latch RESET/ PRESET		40		55	ns
26	t _{AW}	Async. RESET/PRESET Pulse Width	35		45		ns
27	^t ARO	Async. RESET/PRESET to Input Register/Latch Recovery	30		40		ns
28	^t ARI	Async. RESET/PRESET to Input Register/Latch Recovery	20		30		
29	tPZX	I/OE Pin to Output Enable		30		40	ns
30	tpxz *	I/OE Pin to Output Disable		30		40	ns
31	t _{EA}	Input or I/O to Output Enable via PT		35		45	ns
32	t _{ER} *	Input or I/O to Output Disable via PT		35		45	ns

^{*} Output disable times do not include test load RC time constants.

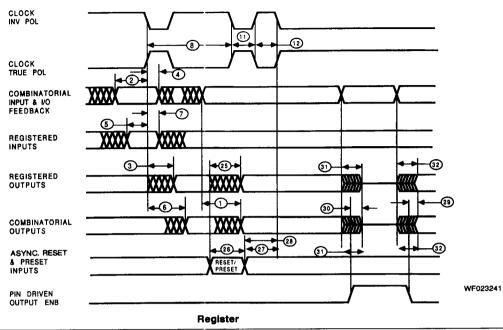


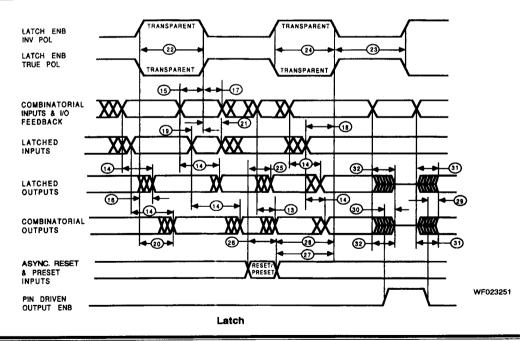
Input/Output Specs (Pin LE Reference)



Input/Output Register Specs (Pin CLK Reference)

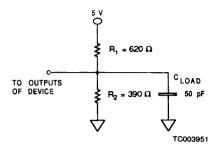
Switching Waveforms





Monolithic MM Memories

Switching Test Circuit



Key to Switching Waveforms

